PNP/NPN Silicon Epitaxial Planar Transistors



CPH3101/3201

0 to 0.1

1 : Base 2 : Emitter 3 : Collector

SANYO : CPH3

DC/DC Converter Applications

[CPH3101/3201]

0.6

9. I

Package Dimensions

2.9

19

0.4

unit:mm 2150

Applications

· Relay drivers, lamp drivers, motor drivers, strobes.

Features

- · Adoption of FBET and MBIT processes.
- · High current capacitance.
- \cdot Low collector-to-emitter saturation voltage.
- · High-speed switching.
- Ultrasmall-sized package permitting applied sets to be made small and slim.
- · High allowable power dissipation.

(): CPH3101

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)30	V
Collector-to-Emitter Voltage	VCEO		(–)30	V
Emitter-to-Base Voltage	VEBO		(–)6	V
Collector Current	IC		(-)2	A
Collector Current (Pulse)	I _{CP}		(-)4	A
Base Current	Ι _Β		(–)400	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)20V, I _E =0			(–)0.1	μA
Emitter Cutoff Current	IEBO	V _{EB} =(-)3V, I _C =0			(–)0.1	μA
DC Current Gain	hFE	V _{CE} =(-)2V, I _C =(-)100mA	200		400	
Gain-Bandwidth Product	fT	V _{CE} =(-)10V, I _C =(-)50mA		150		MHz
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		19(32)		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)1.5A, I _B =(-)75mA		180	400	mV
				(-350)	(-600)	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)1.5A, I _C =(-)75mA		(–)0.85	(–)1.2	V
Marking : CPH3101 : AA, CPH3201 : CA		•		Contin	ued on n	ext page.

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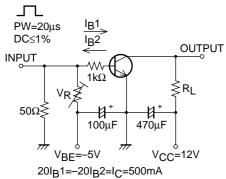
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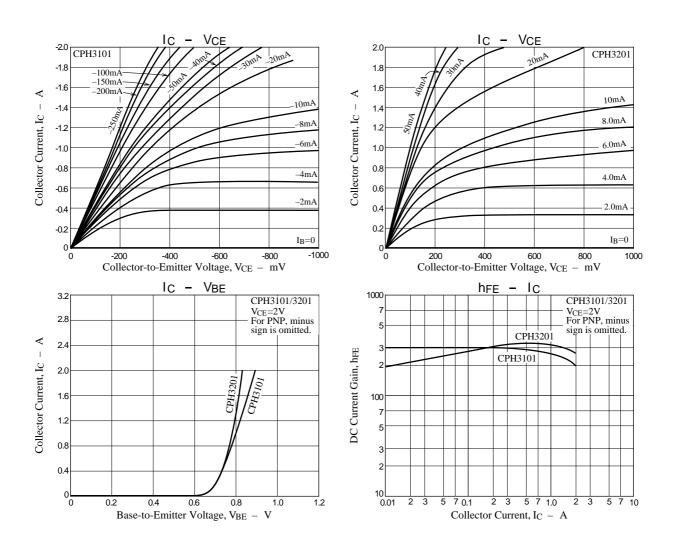
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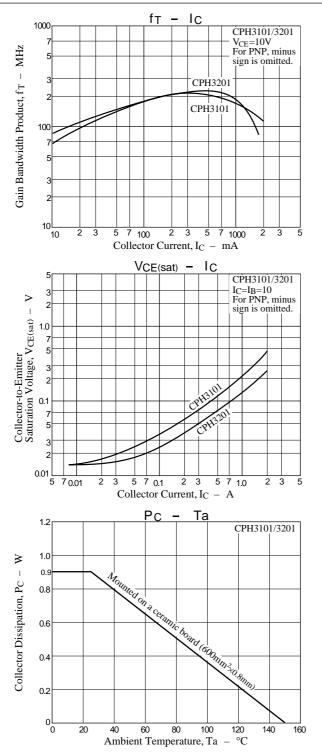
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)10µA, I _E =0	(–)30			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	(–)30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _C =(-)10µA, I _C =0	(–)6			V
Turn-ON Time	ton	See specified test circuit.		60(60)		ns
Storage Time	^t stg	See specified test circuit.		500		ns
				(350)		ns
Turn-OFF Time	t _f	See specified test circuit.		25(25)		ns

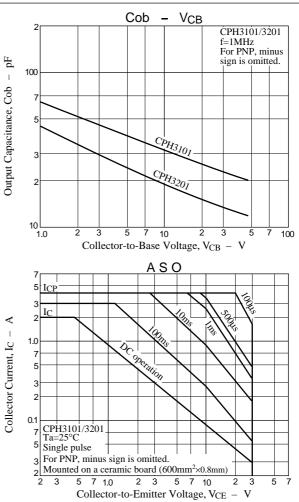
Switching Time Test Circuit



(For PNP, the polarity is reversed.)







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